

On the Involvement of Apical O in CuO-Based Superconductors

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A model based on spectroscopic evidence for holes residing on O in CuO-based superconductors is discussed. Accordingly, superconductivity stems from two separate species, namely O in the CuO₂ planes (^pO) and O in apical positions (^aO, located in BaO planes in YBa₂Cu₃O_x). In YBa₂Cu₃O_x, this leads to two separate phases with $T_c \sim 60$ and $T_c \sim 90$ K, respectively, as these two species become successively oxidized. Predictions are made concerning the behavior of compound families such as Bi₂Sr₂Ca_{n-1}Cu_nO_x. For a given n , two separate superconducting phases should potentially generally obtain as a function of increasing hole concentration with T_c ratios reflecting the ratios of ^pO/^aO.

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Introduction

We discuss in the following a model according to which two contributions to superconductivity can exist in CuO-based superconductors (see (1) for review and T_c data), namely one from O in CuO₂ planes (^pO) and one from apical O (^aO). The latter are O atoms coordinated in the plane with Ba in YBa₂Cu₃O_x. These two species are generally found in CuO-based ceramic superconductors and we shall attempt to show that their relative amounts and oxidation states dictate the magnitude of the superconducting transition temperature. Both types of O are a result of perovskite stacking. As outlined earlier (e.g., Ref. (2)), the simple cubic perovskite stacks a $M^{2+}O$ (B site) layer on top of a $M^{4+}O_2$ (A site) layer which is turned by 90°. This general

principle is maintained in complex superconducting perovskites. As examples in compound series such as YBa₂Cu_nO_x, Bi₂Sr₂Ca_{n-1}Cu_nO_x, or their TI analogs, (CuO₂)_n planes are followed by alkaline earth oxide planes (e.g., BaO as B site analogs). The CuO₂ planes are the source of the ^pO and the B sites produce ^aO. More specifically, the YBa₂Cu₃O_x stacking can be written as (^pCu ^pO₂) (Y) (^pCu ^pO₂) (Ba ^aO) (^cCuO) (Ba^aO) where ^cCu or chain Cu is stacked symmetrically between BaO planes. Increasing x results in a rise in T_c with two plateaus of ~ 60 and ~ 90 K, respectively (e.g., Refs. (3, 4)). Formally speaking, ^cCu is 1+ with $x = 6$ and rises to 3+ with $x = 7$. In reality, this charge is partly delocalized beyond $x = 6.5$ and holes can be found on O (5). Superconductivity is now considered to require CuO₂ planes

only rather than chains (e.g., as many chainless compounds are superconductors) and the mechanism for T_c plateaus should be connected with regions near these planes. We shall in the following present pertinent data and subsequently discuss them in the frame of our model.

Results

We take as our point of departure the findings that in $\text{YBa}_2\text{Cu}_3\text{O}_x$ two superconducting modifications exist with $T_c \sim 60$ and $T_c \sim 90$ K, respectively, as schematically shown in Fig. 1 together with proposed valencies (spinoidal decompositions have been implicated (6) in producing these plateaus, but the preparation temperatures and details of the magnetic signals in question rule this out at least for the materials in Refs. (3, 4)). A series of papers on partly substituted materials (4, 7, 8) have shown that electron filling is responsible for plateaus in T_c rather than the O filling x . As an example, $T_c \sim 90$ K can be obtained with relatively low x in compounds such as $\text{Y}_{1-y}\text{M}_y\text{Ba}_2\text{Cu}_3\text{O}_x$ with $M = \text{Ca}$ or Na . This rules out the implications of superstructure in ${}^c\text{CuO}$ or any of its local configurations. In order to explain the existence of plateaus in T_c , we must assume that systems (such as ${}^c\text{Cu}$) other than the one supporting superconductivity gradually change in charge with x . We assume, therefore, that ${}^c\text{CuO}$ stays insulating and functions as a charge buffer while the mechanism providing T_c plateaus must be in the plane or its vicinity.

The mechanism behind charge delocalization is outlined in the following schematic representation. Accordingly, we write formally $(\text{Y}^{\text{pCu}}\text{Cu}_2^+ \text{pO}_4)^-(\text{Ba}_2 \text{aO}_2)$ (${}^c\text{Cu}^{1+}\text{O}_0$) $^{1+}$ for $x = 6$ and $(\text{Y}^{\text{pCu}}\text{Cu}_2^+ \text{pO}_4)^-(\text{Ba}_2 \text{aO}_2)(\text{Cu}^{3+}\text{O}_0)^{1+}$ for $x = 7$. This writing emphasizes the changing Cu oxidation and the negative charge accumulation near ${}^p\text{Cu}$. We note that holes (5) are found on O and search for a representation of

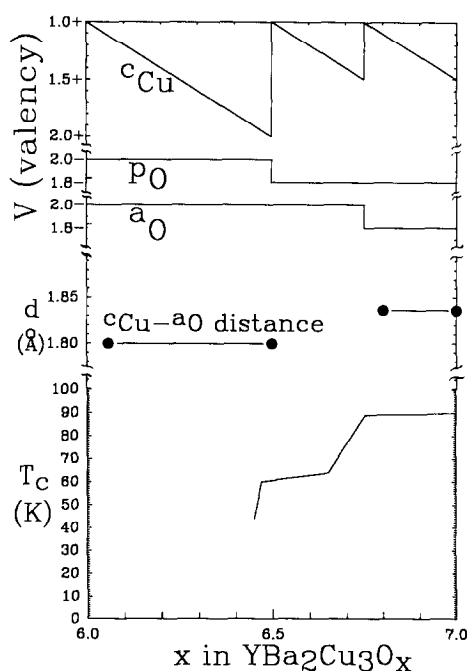


FIG. 1. Schematic representation of superconducting transition temperatures (T_c), distance ${}^c\text{Cu}$ ${}^a\text{O}$ (d) and valencies, (v), as a function of x in $\text{YBa}_2\text{Cu}_3\text{O}_x$. Data are from Refs. (3, 4). Valencies are calibrated to assumptions given in the text. Actual hole to O ratios may be closer to 1:12 rather than 1:4 assumed here. No data are available for d ${}^c\text{Cu}$ ${}^a\text{O}$ between $x = 6.5$ and $x = 6.75$ and the specific sample with $x = 0.5$ was not yet superconducting.

this charge delocalization. Clearly, there must be two qualitatively different O responsible for two plateaus in a ratio near 2:1. ${}^p\text{O}$ and ${}^a\text{O}$ are the natural choices especially as O in ${}^c\text{Cu}$ "plane" are part of the insulating charge reservoir. The following is the proposed sequence of events with increasing x in $\text{YBa}_2\text{Cu}_3\text{O}_x$:

$x = 6$. This semiconducting composition can be represented as $(\text{Y}^{3+} \text{Cu}_2^{2+} \text{pO}_4^{2-})^{1-}(\text{Ba}_2^{2+} \text{aO}_2^{2-})(\text{Cu}^{1+}\text{O}_0)^{1+}$. Accordingly, Ba is attracted to ${}^p\text{O}$, and ${}^a\text{O}$ to ${}^c\text{Cu}$. The short ${}^c\text{Cu}$ ${}^a\text{O}$ distance is shown in Fig. 1 as a function of x derived from Ref. (3). With increasing x , ${}^c\text{Cu}$ increases from 1+ to 2+ but charge stays localized.

$x = 6.5$. Near $x = 0.5$ charge delocalization and rearrangement resulting in $T_c \sim 60$ K occur. On low temperature-low O pressure synthesis (3), this transition occurs already near $x = 6.4$ and entails a stepwise decrease in the c axis. This change appears also to be reflected in an increasing distance ${}^c\text{Cu}^a\text{O}$ (Fig. 1) (although the data in Fig. 1 for $x = 6.5$ are for a yet nonsuperconducting material). The rearrangement toward more positive charge near ${}^p\text{Cu}$ and less positive charge at ${}^c\text{Cu}$ is also reflected by the decreasing a axis (influencing ${}^p\text{Cu}$) and increasing b axis (primarily influencing ${}^c\text{Cu}$). We shall not attempt to quantitatively determine the extent of this charge rearrangement and for simplicity, assume that ${}^c\text{Cu}$ changes from $2+$ to $1+$. This is represented as $(\text{Y}^{3+}\text{Cu}_2^{2+} \text{PO}_3^{2-} \text{PO}^{1-})^0(\text{Ba}_2 \text{aO}_2^-) ({}^c\text{Cu}^{1+}\text{O}_{0.5})^0$ showing a formal peroxide state PO^{1-} . This means that one hole can flow into four ${}^p\text{O}$ (it is gratifying that the second charge transfer near $x = 0.75$ occurs with the same stoichiometric proportions namely half a hole for two ${}^a\text{O}$). The driving force for this charge rearrangement is obviously the reduction of excess negative charge near ${}^p\text{Cu}$. Increasing x will now increase the charge on ${}^c\text{Cu}$. The ${}^c\text{Cu}$ system, however, stays localized and does not contribute to T_c so that T_c can stay at a plateau. Near $x = 6.67$, positive charge starts to flow also into ${}^a\text{O}$. The process is complete near $x = 0.75$ (see stoichiometric considerations

above) and we take this composition as a separate superconducting phase.

$x = 6.75$. This is the beginning of the $T_c \sim 90$ K plateau. We assume that charge disproportion has again resulted in ${}^c\text{Cu}^{1+}$ and the formation of a formal peroxide now also on ${}^a\text{O}$ according to $(\text{Y}^{3+} \text{PCu}_2^{2+} \text{PO}_3^{2-} \text{PO}^{1-})^0(\text{Ba}_2 \text{aO}_{1.5}^- \text{aO}_{0.5}^-)^{0.5+} ({}^c\text{Cu}^{1+}\text{O}_{0.75})^{0.5-}$. In this range, the ${}^p\text{Cu} \text{ }^a\text{O}$ distance shortens on entering the superconducting state (9). On increasing x , ${}^c\text{Cu}$ valency increases, but these charges again stay localized.

Discussion

Several experimental facts and predictions follow naturally from a correlation of T_c with ${}^p\text{O}$ and ${}^a\text{O}$, respectively. The numbers of $x = 6.5$ and $x = 6.75$ for the onsets of the plateaus in T_c in $\text{YBa}_2\text{Cu}_3\text{O}_x$ can be naturally understood as a result of the need for a specified number of holes (e.g., one hole per four O) in both cases. This results in one formal peroxide, $(\text{O}_2)^{2-}$ per eight O and could possibly give an indication for an actual mechanism of superconductivity involving metallic O by electronic transport of a peroxide-type unit through polarization effects.

From the ratios of four ${}^p\text{O}$ two ${}^a\text{O}$ and $T_c \sim 60$ to 90 K, we assign $T_c \sim 30$ K per two O. These ratios change in families such as $\text{Bi}_2\text{Sr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_x$ (Table I) and a generalized prediction can be given for potential maximum and minimum values of T_c (K) of $30n + 30$ and $30n$, respectively, where n is the number of CuO_2 planes (not including, e.g., ${}^c\text{Cu}$). Experimental data of T_c are given in Table II for a variety of ceramic superconductors. It is seen that experimental T_c either reflect predicted maximum (full ${}^p\text{O}$ and ${}^a\text{O}$ involvement) or minimum values (${}^p\text{O}$ involvement only). As an example for $\text{Bi}_2\text{Ca}_{n-1}\text{Sr}_2\text{Cu}_n\text{O}_x$ with $n = 3$, the ratio ${}^p\text{O}/{}^a\text{O}$ is 3:1 and we expect possible plateaus in T_c of 90 and 120 K. These plateaus could become developed by either changing O

TABLE I
EXPECTED T_c PLATEAUS IN COMPOUND
SERIES SUCH AS $\text{Bi}_2\text{Sr}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_x$

n	${}^p\text{O}/{}^a\text{O}$	Expected T_c (K) plateaus
1	1:1	30 and 60 K
2	2:1	60 and 90 K
3	3:1	90 and 120 K
4	4:1	120 and 150 K

TABLE II
CHARGE POLARIZATIONS AND SUPERCONDUCTING HOLES (ASTERISKS) IN CERAMIC SUPERCONDUCTORS

Material ^a	T_c (K) ^b
$(\text{RCu}_2^{2+} \text{ } ^p\text{O}_4^*)^{-1}(\text{Ba}_2 \text{ } ^a\text{O}_2)(\text{Cu}^{2+}\text{O}_{0.5})^{+1}$	60
$(\text{RCu}_2^{2+} \text{ } ^p\text{O}_4^*)^{-1}(\text{Ba}_2 \text{ } ^a\text{O}_2^*)(\text{Cu}^{3+}\text{O}_1)^{+1}$	90
$(\text{RCu}_2^{2+} \text{ } ^p\text{O}_4^*)^{-1}(\text{Ba}_2 \text{ } ^a\text{O}_2^*)(\text{Cu}^{2.5+}\text{O}_2)^{+1}$	80
$(\text{Ca}_0\text{Cu}^{2+} \text{ } ^p\text{O}_2^*)^{-2}(\text{Sr}_2 \text{ } ^a\text{O}_2)(\text{Bi}_2\text{O}_2)^{-2}$	20
$(\text{Ca}_1\text{Cu}_2^{2+} \text{ } ^p\text{O}_2^*)^{-2}(\text{Sr}_2 \text{ } ^a\text{O}_2^*)(\text{Bi}_2\text{O}_2)^{-2}$	90
$(\text{Ca}_2\text{Cu}_3^{2+} \text{ } ^p\text{O}_6^*)^{-2}(\text{Sr}_2 \text{ } ^a\text{O}_2^*)(\text{Bi}_2\text{O}_2)^{-2}$	120

^a Asterisks indicate the location of superconducting holes generated by changes in ^cCu valency or by non-stoichiometry (not represented). Maximum predicted T (K) is $30n + 30$. Where this is not reached, ^aO are not involved in superconductivity.

^b Maximum values reported (e.g., Ref. (1)).

content x or cation charge. For reports of higher T_c than given in the above $T_c(n)$ relationship, caution concerning phase purity appears in order. However, $T_c \sim 90$ K for $\text{Ti}_2\text{Ba}_2\text{CuO}_6$ may actually indicate that even the O in the Ti_2O_2 planes can become superconducting and that further steps in T_c through coupling of all planes may be possible. On the other hand, the fact that $n = 4$ in $\text{TiBa}_2\text{Ca}_{n-1}\text{Cu}_n\text{O}_x$ has so far only shown $T_c \sim 122$ K (comparable or slightly lower than for $n = 3$) may suggest an intrinsic saturation or that in this compound, ^aO has not been turned superconducting yet (e.g., due to lack of oxidation). When ^aO also becomes superconducting (e.g., through partial Na substitution for Ca), we would expect $T_c \sim 150$ K on the simple model. With higher n , this linear progression in T_c can be assumed to saturate, although considerably higher values should yet be attainable. In this connection, the $n = \infty$ compound $(\text{CaSr})\text{CuO}_2$ with partial substitution (e.g., Na for Ca) appears interesting.

Materials with $n = 1$ also show a tendency to exclusion of ^aO in superconductivity ($T_c = 30$ rather than 60 K). An exception is $(\text{Ti,Bi})\text{Sr}_2\text{CuO}_5$ with $T_c \sim 50$ K. However, $\text{Bi}_2\text{Sr}_2\text{CuO}_x$ has only $T_c \sim 20$ K. Also,

$(\text{LaSr})_2\text{CuO}_4$, while not fully comparable structurally, has $T_c \sim 30$ K. In this respect, it is interesting to note that $(\text{KBa})\text{BiO}_3$ has $T_c \sim 30$ K. This appears to indicate that O in the BiO_2 plane has become fully superconducting in analogy with $n = 1$ phases such as $\text{Bi}_2\text{Sr}_2\text{CuO}_x$. $\text{Ba}(\text{PbBi})\text{O}_3$ has a lower T_c (14 K) because of the disruption of the relevant plane through disordered substitution.

We have in the above not attempted to arrive at a quantitative determination of charge transfer. Such a determination may be possible in an indirect way. Indications exist (10) that ^pCu is formally $2.25 +$ in $n = 2$ materials such as $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_x$. As these materials can have $T_c \sim 90$ K, both ^aO and ^pO must superconduct. The 0.5 holes have, therefore, to be distributed over 6 O. This indicates one hole per 12 O rather than 4 O as assumed above. This also alters the assumed valencies on ^cCu in $\text{YBa}_2\text{Cu}_3\text{O}_x$, but does not change the general ideas.

The location of ^aO relative to ^pCu appears to be of importance concerning the potential for involving ^aO in superconductivity. In this respect, we note that $\text{LaBa}_2\text{Cu}_3\text{O}_x$ can easily be obtained with $T_c \sim 60$ K, but it is difficult to obtain (4) the $T_c \sim 90$ K phase even though x can be near 7. We assign this difficulty to structural peculiarities in the location of ^aO. Either the relative distances are unsuitable or partial LaBa substitutions near ^aO produce sufficient disorder in the positions to preclude superconductivity on this site. Strong pressure dependencies of T_c can be anticipated in regions where ^aO is electronically and structurally poised to become superconducting.

An important question concerning valencies is the one of limiting O uptake. For $\text{YBa}_2\text{Cu}_3\text{O}_x$, pressure-composition (p, x) isotherms show strong saturation near $x = 7$. If this were only reflecting a structural argument, then materials such as $(\text{Y Ca})\text{Ba}_2\text{Cu}_3\text{O}_x$ should also show (4, 9) limiting x near 7. Experimentally, however, $x < 7$,

indicating that electron count determines x . For $Y_{0.5}Na_{0.5}Ba_2Cu_3O_{6.5}$ (4), or a fictitious $CaBa_2Cu_3O_x$ maximum $x = 6.5$. In representation with variable Cu valency, this is $(Ca^{2+}Cu_2^{2+}O_4^*)^{2-}(Ba_2O_2^*)(^cCu^{3+}O_{0.5})^{2+}$ where the asterisks indicate hole formation potential. This shows that the condition for valencies of 2+ for pCu and 3+ for cCu can be used to formally determine maximum x . It is possible that this fact represents a more fundamental aspect of charge delocalization involving $^cCu^{3+}$ in temporal charge fluctuations to pO and aO .

Conclusion

From spectroscopic evidence, we conclude that superconducting holes reside primarily on O. A natural correlation for $YBa_2Cu_3O_x$ is the one of holes on plane O to be responsible for $T_c \sim 60$ K. When holes penetrate to apical oxygens, $T_c \sim 90$ K. This can be generalized to other known superconductors and leads to the expectation of different T_c plateaus depending on the ratio of $^pO/^aO$ and their degree of oxidation. In cases where the oxygen content is fixed, these plateaus will have to be developed through partial substitutions with metals of different valencies. As evidence for pO aO involvement, we take the comparable number of holes per atom for the two species (in the relation of 2 : 1 as given by stoichiome-

try in $YBa_2Cu_3O_x$), the relative magnitude of the two T_c plateaus, and the motion of aO relative to cCu with x . The model involving apical O extends the idea of charge fluctuations from Cu, where no straightforward signs for Cu^{3+} are reported, to the O system. This naturally allows explanation of stable states (T_c plateaus) with x involving pO and aO . If one involves the two Cu with individual contributions to superconductivity, the existence of plateaus cannot be easily explained. If only pCu is considered, there is no obvious way to explain two electronically distinct states resulting in two T_c plateaus.

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